## International IER Rectifier

$$
\begin{gathered}
\mathrm{I}_{\mathrm{F}(\mathrm{AV})}=12 \mathrm{Amp} \\
V_{R}=30 \mathrm{~V}
\end{gathered}
$$

## Major Ratings and Characteristics

$\left.\begin{array}{|l|c|c|}\hline \text { Characteristics } & \text { Values } & \text { Units } \\ \hline \mathrm{I}_{\mathrm{F}(\mathrm{AV})} \text { Rectangular } \\ \text { waveform }\end{array}\right)$

## Description/ Features

The 12CWQ03FN surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, free-wheeling diodes, battery charging, and reverse battery protection.

- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
Case Styles


## Voltage Ratings

| Partnumber | 12CWQ03FN |
| :--- | :---: |
| $\mathrm{V}_{\mathrm{R}}$ Max. DC Reverse Voltage $(\mathrm{V})$ | 30 |
| $\mathrm{~V}_{\mathrm{RWM}}$ Max. Working Peak Reverse Voltage $(\mathrm{V})$ |  |

## Absolute Maximum Ratings

|  | Parameters | 12CWQ... | Units | Conditions |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{I}_{\text {(AV) }}$ | Max.AverageForward (PerLeg) Current*SeeFig. 5 (PerDevice) | $\begin{gathered} 6 \\ 12 \end{gathered}$ | A | $50 \%$ duty cycle @ $\mathrm{T}_{\mathrm{C}}=135^{\circ} \mathrm{C}$, rectangularwave form |  |
| $\mathrm{I}_{\text {FSM }}$ | Max.PeakOneCycleNon-Repetitive Surge Current (PerLeg) *SeeFig. 7 | 320 130 | A | $5 \mu$ s Sine or $3 \mu \mathrm{~s}$ Rect. pulse 10 ms Sine or $6 \mathrm{~ms} \mathrm{Rect}$. pulse | Following any rated load condition and with rated $V_{\text {RRM }}$ applied |
| $\mathrm{E}_{\text {AS }}$ | Non-Rep. AvalancheEnergy (PerLeg) | 10 | mJ | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}, \mathrm{I}_{\mathrm{AS}}=2.0 \mathrm{Amps}, \mathrm{L}=5 \mathrm{mH}$ |  |
| $\mathrm{I}_{\text {AR }}$ | RepetitiveAvalancheCurrent (PerLeg) | 2.0 | A | Current decaying linearly to zero in $1 \mu \mathrm{sec}$ Frequency limited by $\mathrm{T}_{\mathrm{J}}$ max. $\mathrm{V}_{\mathrm{A}}=1.5 \times \mathrm{V}_{\mathrm{R}}$ typical |  |

Electrical Specifications

| Parameters |  | 12CWQ... | Units | Conditions |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Max. Forward Voltage Drop <br> (Per Leg) * See Fig. 1 <br> (1) | 0.47 | V | @ 6A | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ |
|  |  | 0.55 | V | @ 12A |  |
|  |  | 0.37 | V | @ 6A | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |
|  |  | 0.49 | V | @ 12A |  |
| $\mathrm{I}_{\mathrm{RM}}$ | Max. Reverse Leakage Current (Per Leg) * See Fig. 2 | 3 | mA | $\mathrm{T}_{\mathrm{J}}=25^{\circ} \mathrm{C}$ | $V_{R}=$ rated $V_{R}$ |
|  |  | 58 | mA | $\mathrm{T}_{\mathrm{J}}=125^{\circ} \mathrm{C}$ |  |
| $\mathrm{V}_{\mathrm{F} \text { (TO) }}$ | Threshold Voltage | 0.196 | V | $\mathrm{T}_{\mathrm{J}}=\mathrm{T}_{\mathrm{J}}$ max. |  |
| $\mathrm{r}_{\mathrm{t}}$ | Forward Slope Resistance | 21.66 | $\mathrm{m} \Omega$ |  |  |  |
| $\mathrm{C}_{\text {T }}$ | Typ. Junction Capacitance (PerLeg) | 590 | pF | $\mathrm{V}_{\mathrm{R}}=5 \mathrm{~V}_{\mathrm{DC}}$ (t | t signal range 100 Khz to 1 Mhz ) $25^{\circ} \mathrm{C}$ |
| $\mathrm{L}_{\text {s }}$ | Typical Series Inductance (Per Leg) | 5.0 | nH | Measured le | to lead 5 mm from package body |

(1) Pulse Width < 300 $\mu$ s, Duty Cycle $<2 \%$

Thermal-Mechanical Specifications

|  | Parameters | 12CWQ... | Units | Conditions |
| :---: | :---: | :---: | :---: | :---: |
| $\mathrm{T}_{\mathrm{J}}$ | Max. Junction Temperature Range (*) | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |  |
| $\mathrm{T}_{\text {stg }}$ | Max. Storage Temperature Range | -55 to 150 | ${ }^{\circ} \mathrm{C}$ |  |
| $\mathrm{R}_{\text {thJc }}$ | Max. Thermal Resistance (PerLeg) Junction to Case (PerDevice) | 3.0 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ | DCoperation *SeeFig. 4 |
|  |  | 1.5 |  |  |
| wt | Approximate Weight | 0.3(0.01) | g(oz.) |  |
|  | Case Style | D-Pak |  | Similar to TO-252AA |
|  | MarkingDevice | 12CWQ03FN |  |  |

[^0]International


Fig. 1-Max. Forward Voltage Drop Characteristics (PerLeg)


Fig. 2-Typical Values Of Reverse Current Vs. Reverse Voltage (PerLeg)


Fig. 3-Typical Junction Capacitance Vs. Reverse Voltage (PerLeg)


Fig. 4-Max. Thermal Impedance $Z_{\text {thJc }}$ Characteristics (PerLeg)


Fig. 5-Max. Allowable Case Temperature Vs. Average Forward Current (PerLeg)


Fig. 6-Forward Power Loss Characteristics (PerLeg)


Fig.7-Max. Non-Repetitive Surge Current (PerLeg)
(2) Formula used: $\mathrm{T}_{\mathrm{C}}=\mathrm{T}_{\mathrm{J}}-\left(\mathrm{Pd}+\mathrm{Pd}_{\mathrm{REv}}\right) \times \mathrm{R}_{\text {thJC }}$;
$P d=$ Forward Power Loss $=I_{F(A V)} \times V_{F M} @\left(I_{F(A V)} / D\right)$ (see Fig. 6);
$\mathrm{Pd}_{\mathrm{REV}}=$ Inverse Power Loss $=\mathrm{V}_{\mathrm{R} 1} \times \mathrm{I}_{\mathrm{R}}(1-\mathrm{D}) ; \mathrm{I}_{\mathrm{R}} @ \mathrm{~V}_{\mathrm{R} 1}=80 \%$ rated $\mathrm{V}_{\mathrm{R}}$

Outline Table


Part Marking Information


Tape \& Reel Information


Ordering Information Table


Data and specifications subject to change without notice. This product has been designed and qualified for AEC Q101 Level. Qualification Standards can be found on IR's Web site.

## International <br> ISR Rectifier

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[^0]:    $\left.{ }^{*}\right) \frac{d P t o t}{d T j}<\frac{1}{R t h(j-a)}$ thermal runaway condition for a diode on its own heatsink

